

37. (Twice Amended) A semiconductor laser device, comprising:

a semiconductor laser configured to emit a laser beam;

a cylindrical lens configured to allow the laser beam emitted from the semiconductor laser to pass therethrough;

detecting means for detecting the laser beam passed through the cylindrical lens;

and

intensity changing means for changing the intensity of a portion of the laser beam depending upon the wavelength of the laser beam, the intensity changing means being disposed in an optical path between the semiconductor laser and the detecting means such that another portion of the laser beam is detected by the detecting means without impinging upon the intensity changing means.

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